# International Rectifier

#### Series PVN012

HEXFET® Power MOSFET Photovoltaic Relay

Microelectronic Power IC Relay

Single Pole, Normally Open, 0-20V, 2.5A AC/ 4.5A DC

#### **General Description**

The PVN012 Series Photovoltaic Relay at 100 milliohms features the lowest possible on-state resistance in a miniature package — lower than a comparable reed relay.

The PVN012 is a single-pole, normally open solidstate relay. It utilizes a GenerationV HEXFET output switch, driven by an integrated circuit photovoltaic generator of novel construction. The output switch is controlled by radiation from a GaAlAs light emitting diode (LED) which is optically isolated from the photovoltaic generator.

These units exceed the performance capabilities of electromechanical relays in life, sensitivity, stable on-resistance, miniaturization, magnetic insensitivity and ruggedness. They are ideally suited for switching high currents or low level signals without distortion or injection of electrical noise.

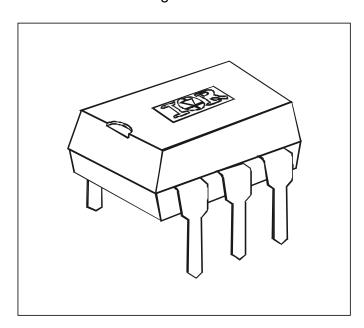
Series PVN012 Relays are packaged in a 6-lead molded DIP package with either through-hole or surface mount (gull-wing) terminals. They are available in standard plastic shipping tubes or on tape-and-reel. Please refer to part identification information opposite.

### **Applications**

- Portable Electronics
- Programmable Logic Controllers
- Computers and Peripheral Devices
- Audio Equipment
- Power Supplies and Power Distribution
- Instrumentation

#### **PVN012 Features**

- 100mΩ On-Resistance ■
- GenV HEXFET output ■
- Bounce-free operation ■
- 2.5 4.5 Amp capacity ■
- Linear AC/DC operation ■
- 4,000 V<sub>RMS</sub> I/O isolation
  - Solid-State reliability ■
- UL recognized and CSA certified ■



#### **Part Identification**

PVN012 through-hole PVN012S surface-mount

PVN012S-T surface-mount, Tape and Reel

(HEXFET is the registered trademark for International Rectifier Power MOSFETs)

## Series PVN012 — HEXFET® Photovoltaic Relay

International

TOR Rectifier

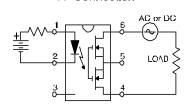
**Electrical Specifications** (-40°C  $\leq$  T<sub>A</sub>  $\leq$  +85°C unless otherwise specified)

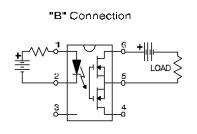
INPUT CHARACTERISTICS	Limits	Units
Minimum Control Current (see figure 1)	3.0	mA
Maximum Control Current for Off-State Resistance @ T <sub>A</sub> = +25°C	0.4	mA
Control Current Range (Caution: current limit input LED, see figure 6)	3.0 to 25	mA
Maximum Reverse Voltage	7.0	V

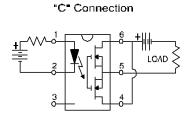
OUTPUT CHARACTERISTICS	Limits	Units
Operating Voltage Range	0 to ±20	V(DC or AC peak)
Maximum Continuous Load Current @ T <sub>A</sub> =+40°C, 5mA Control (see figure 1)		
A Connection	2.5	A (DC or AC)
B Connection	3.0	A (DC)
C Connection	4.5	A (DC)
Maximum Pulsed Load Current @T <sub>A</sub> =+25°C, (100 ms @ 10% duty cycle)		
A Connection	6.0	A (DC or AC)
Maximum On-State Resistance @T <sub>A</sub> =+25°C, for 1A pulsed load, 5mA Control (see figure 4)		
_A Connection	100	
B Connection	65	mΩ
C Connection	40	
Minimum Off-State Resistance @ T <sub>A</sub> =+25°C, ±16V <sub>DC</sub>	0.16 x 10 <sup>8</sup>	Ω
Maximum Off-State Leakage @T <sub>A</sub> =+25°C, ±16V <sub>DC</sub> (see figure 5)	1.0	mA
Maximum Turn-On Time @T <sub>A</sub> =+25°C (see figure 7), for 1A, 20 V <sub>DC</sub> load, 5mA Control	5.0	ms
Maximum Turn-Off Time @T <sub>A</sub> =+25°C (see figure 7), for 1A, 20 V <sub>DC</sub> load, 5mA Control	0.5	ms
Maximum Output Capacitance @ 20V <sub>DC</sub> (see figure 2)	300	pF

GENERAL CHARACTERISTICS		Limits	Units
Minimum Dielectric Strength, Input-Output		4000	VRMS
Minimum Insulation Resistance, Input-Output, @T <sub>A</sub> =+25°C, 50%RH, 100V <sub>DC</sub>		1012	Ω
Maximum Capacitance, Input-Output		1.0	pF
Maximum Pin Soldering Temperature (10 seconds max	kimum)	+260	
Ambient Temperature Range:	Operating	-40 to +85	°C
	Storage	-40 to +100	

# Connection Diagrams "A" Connection







### Series PVN012 — HEXFET® Photovoltaic Relay

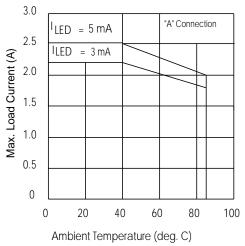
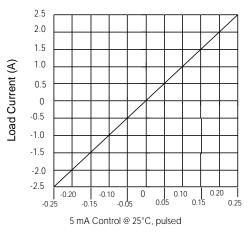


Figure 1. Current Derating Curves\*



Connection "A" Voltage Drop (Vdd)
Figure 3. Linearity Characteristics

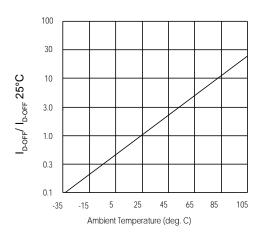
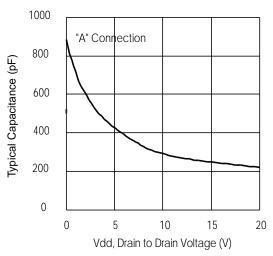


Figure 5. Typical Normalized Off-State Leakage



**Figure 2. Typical Output Capacitance** 

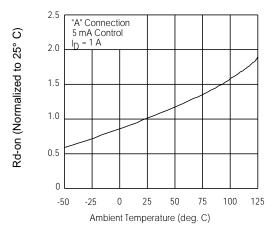


Figure 4. Typical Normalized On-Resistance

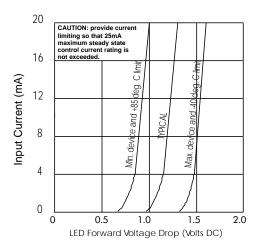
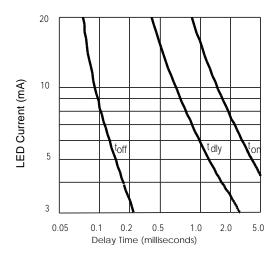


Figure 6. Input Characteristics (Current Controlled)

<sup>\*</sup> Derating of 'B' and 'C' connection at +85°C will be 70% of that specified at +40°C and is linear from +40°C to +85°C.



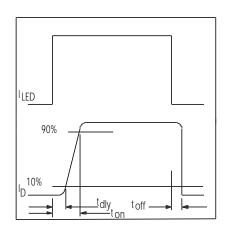
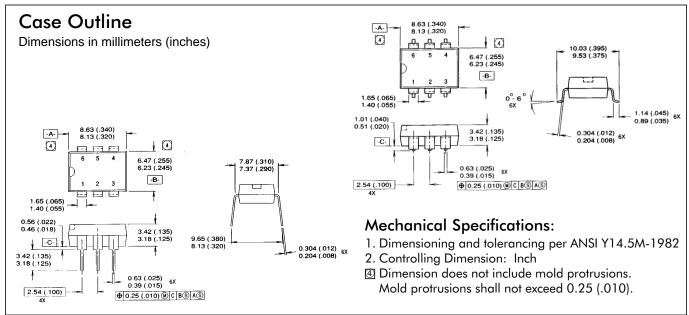


Figure 7. Typical Delay Times

Figure 8. Delay Time Definitions



# International Rectifier

WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, Tel: (310) 322 3331 EUROPEAN HEADQUARTERS: Hurst Green, Oxted, Surrey RH8 9BB, UK Tel: ++ 44 1883 713215 IR CANADA: 7321 Victoria Park Ave., Suite 201, Markham, Ontario L3R 2Z8, Tel: (905) 475 1897 IR GERMANY: Saalburgstrasse 157, 61350 Bad Homburg Tel: ++ 49 6172 96590

IR ITALY: Via Liguria 49, 10071 Borgaro, Torino Tel: ++ 39 11 451 0111

IR FAR EAST: K&H Bldg., 2F, 3-30-4 Nishi-Ikeburo 3-Chome, Toshima-Ku, Tokyo, Japan 171 Tel: ++ 81 3 3983 0641 IR SOUTHEAST ASIA: 315 Outram Road, #10-02 Tan Boon Liat Building, Singapore 0316 Tel: ++ 65 221 8371

http://www/irf.com/

Data and specifications subject to change without notice. 9/96